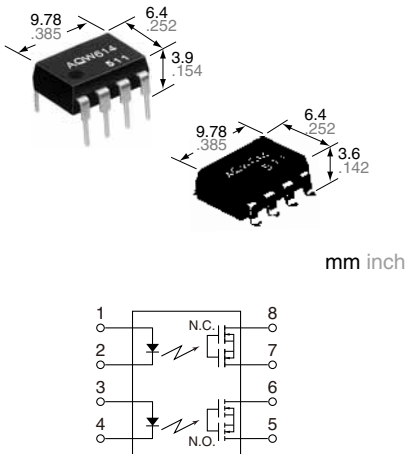




Both NO and NC contacts incorporated in a DIP8-pin package

**PhotoMOS®
GU 1 Form A & 1 Form B
(AQW614)**



FEATURES

1. Approx. 1/2 the space compared with the mounting of a set of 1 Form A and 1 Form B PhotoMOS
2. Applicable for 1 Form A and 1 Form B use as well as two independent 1 Form A and 1 Form B use
3. Controls load currents up to 0.13 A with 5 mA input current
4. Extremely low closed-circuit offset voltages to enable control of small analog signals without distortion
5. Stable on-resistance

TYPICAL APPLICATIONS

- High-speed inspection machines
- Telephone equipment
- Computers
- Sensing equipment

RoHS compliant

TYPES

	Output rating*		Package	Part No.				Packing quantity	
	Load voltage	Load current		Through hole terminal	Surface-mount terminal		Tube	Tape and reel	
					Tape and reel packing style				
			Tube packing style	Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side				
AC/DC dual use	400 V	100 mA	DIP8-pin	AQW614	AQW614A	AQW614AX	AQW614AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

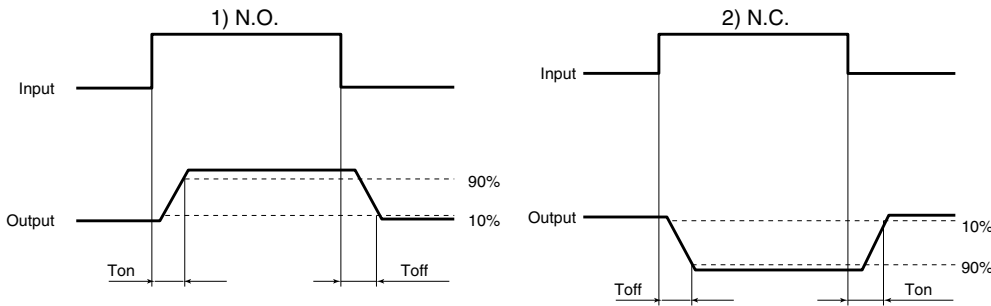
	Item	Symbol	AQW614(A)	Remarks
Input	LED forward current	I _F	50 mA	
	LED reverse voltage	V _R	5 V	
	Peak forward current	I _{FP}	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75 mW	
Output	Load voltage (peak AC)	V _L	400 V	
	Continuous load current	I _L	0.1 A (0.13 A)	Peak AC, DC (): in case of using only 1a or 1b, 1 channel
	Peak load current	I _{peak}	0.3 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}	800 mW	
Total power dissipation		P _T	850 mW	
I/O isolation voltage		V _{iso}	1,500 V AC	Between input and output/between contact sets
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F	

GU 1 Form A & 1 Form B (AQW614)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQW614(A)	Condition
Input	LED operate current	Typical	I_{Fon} (N.O.)	0.9 mA	$I_L = 100$ mA
		Maximum	I_{Foff} (N.C.)	3 mA	
	LED reverse current	Minimum	I_{Foff} (N.O.)	0.4 mA	$I_L = 100$ mA
		Typical	I_{Fon} (N.C.)	0.8 mA	
LED dropout voltage	Typical	V_F	1.25 V (1.14 V at $I_F = 5$ mA)		$I_F = 50$ mA
	Maximum		1.5 V		
Output	On resistance	Typical	R_{on}	27 Ω	$I_F = 5$ mA (N.O.) $I_F = 0$ mA (N.C.) $I_L = 100$ mA within 1 s on time
		Maximum		50 Ω	
	Off state leakage current	Maximum	I_{Leak}	1 μ A	$I_F = 0$ mA (N.O.) $I_F = 5$ mA (N.C.) $V_L = 400$ V
Transfer characteristics	Operate time*	Typical	T_{on} (N.O.)	0.28 ms (N.O.) 0.43 ms (N.C.)	$I_F = 0$ mA \rightarrow 5 mA $I_L = 100$ mA
		Maximum	T_{off} (N.C.)	1 ms	
	Reverse time*	Typical	T_{off} (N.O.)	0.04 ms (N.O.) 0.3 ms (N.C.)	$I_F = 5$ mA \rightarrow 0 mA $I_L = 100$ mA
		Maximum	T_{on} (N.C.)	1 ms	
	I/O capacitance	Typical	C_{iso}	0.8 pF	$f = 1$ MHz
	Maximum	1.5 pF		$V_B = 0$ V	
Initial I/O isolation resistance	Minimum	R_{iso}	1,000 M Ω	500 V DC	

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I_F	5	mA

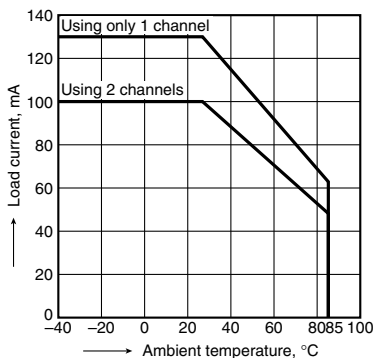
■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

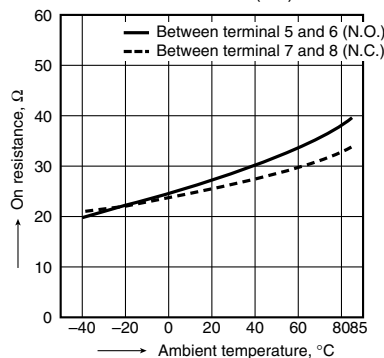
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



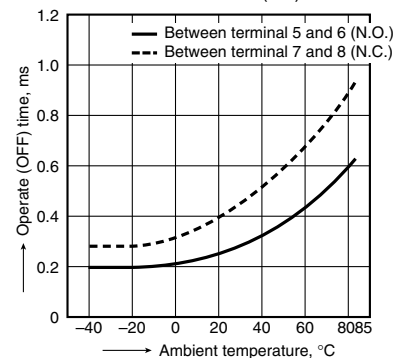
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 5 mA; Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



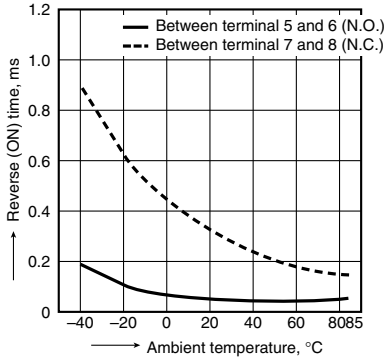
3. Operate time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: 400 V (DC);
Continuous load current: 100 mA (DC)



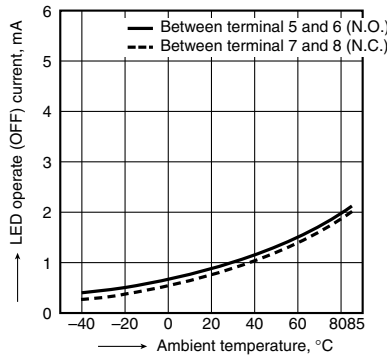
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 100 mA (DC)



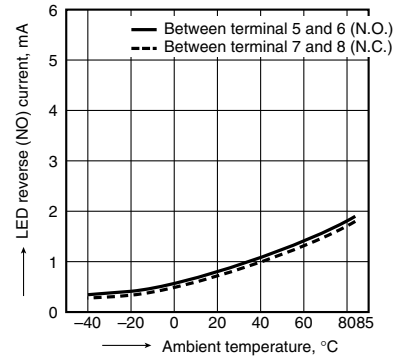
5. LED operate current vs. ambient temperature characteristics

Load voltage: 400 V (DC); Continuous load current: 100 mA (DC)



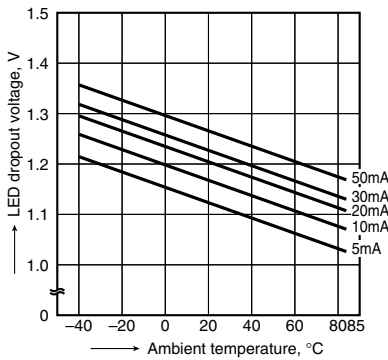
6. LED reverse current vs. ambient temperature characteristics

Load voltage: 400 V (DC); Continuous load current: 100 mA (DC)



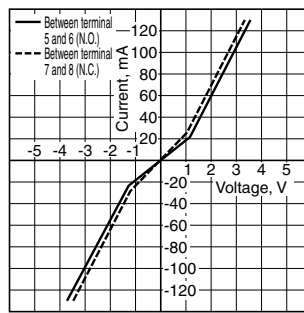
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



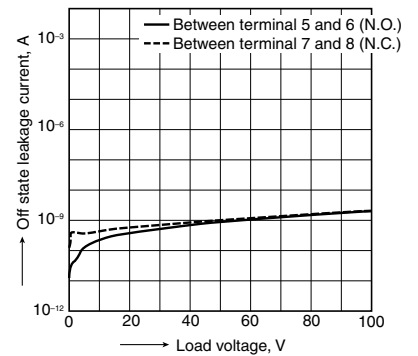
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



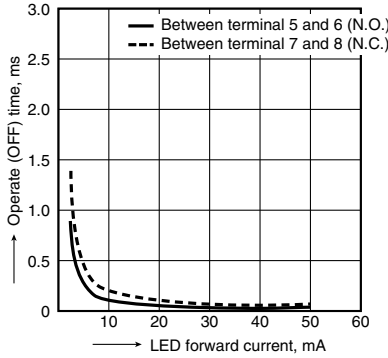
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



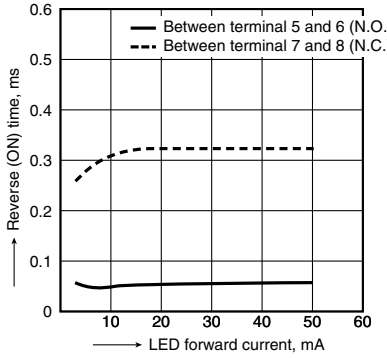
10. Operate time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



11. Reverse time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 0 mA (N.O.), 5 mA (N.C.); Frequency: 1 MHz; Ambient temperature: 25°C 77°F

